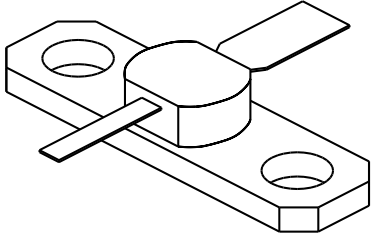

3001

1 Watt - 28 Volts, Class C
Microwave 3000 MHz

<p>GENERAL DESCRIPTION The 3001 is a COMMON BASE transistor capable of providing 1 Watts Class C, RF output power at 3000 MHz. Gold metalization and diffused ballasting are used to provide high reliability and supreme ruggedness. The transistor uses a fully hermetic High Temperature Solder Sealed package.</p>	<p>CASE OUTLINE 55BT, STYLE 1</p> 
<p>ABSOLUTE MAXIMUM RATINGS</p> <p>Maximum Power Dissipation @ 25°C 5 Watts</p> <p>Maximum Voltage and Current</p> <p>BVces Collector to Emitter Voltage 50 Volts BVebo Emitter to Base Voltage 3.5 Volts Ic Collector Current 0.20 A</p> <p>Maximum Temperatures</p> <p>Storage Temperature - 65 to + 200°C Operating Junction Temperature + 200°C</p>	

ELECTRICAL CHARACTERISTICS @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Pout	Power Out	F = 3.0 GHz	1.0			Watt
Pin	Power Input	Vcb = 28 Volts		.14	0.2	Watt
Pg	Power Gain	Po = 1 Watts	7.0	8.5		dB
η_c	Collector Efficiency	As Above		30		%
VSWR₁	Load Mismatch Tolerance	F = 3 GHz, Po = 1 W			30:1	

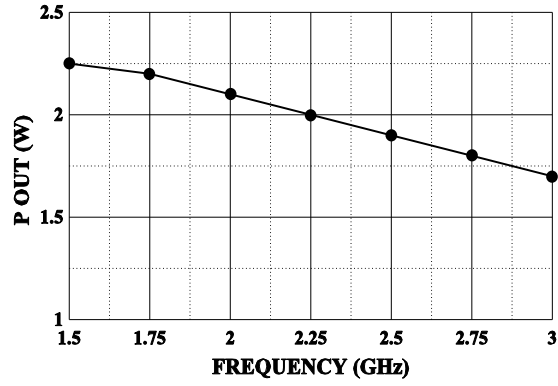
BVces	Collector to Emitter Breakdown	Ic = 10 mA	50			Volts
BVcbo	Collector to Base Breakdown	Ic = 1 mA	45			Volts
BVebo	Emitter to Base Breakdown	Ie = 1 mA	3.5			Volts
Icbo	Collector to Base Current	Vcb = 28 Volts			0.5	mA
h_{FE}	Current Gain	Vce = 5 V, Ic = 100 mA	10			
Cob	Output Capacitance	F = 1 MHz, Vcb = 28 V				
θ_{jc}	Thermal Resistance				35	°C/W

Issue August 1996

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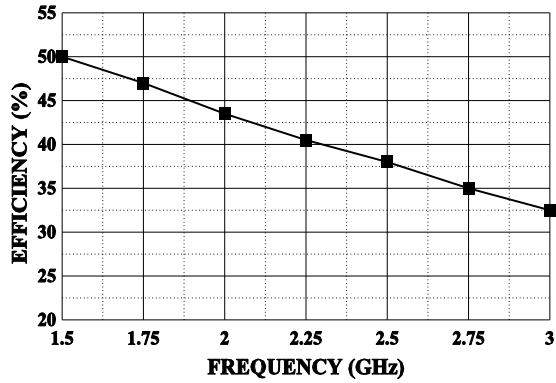
POWER OUTPUT VS FREQUENCY

Vcc=28V, Pin=0.2W



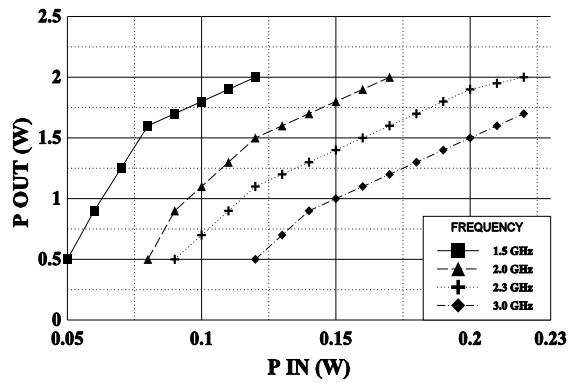
EFFICIENCY VS FREQUENCY

Pin=0.2W, Vcc=28V



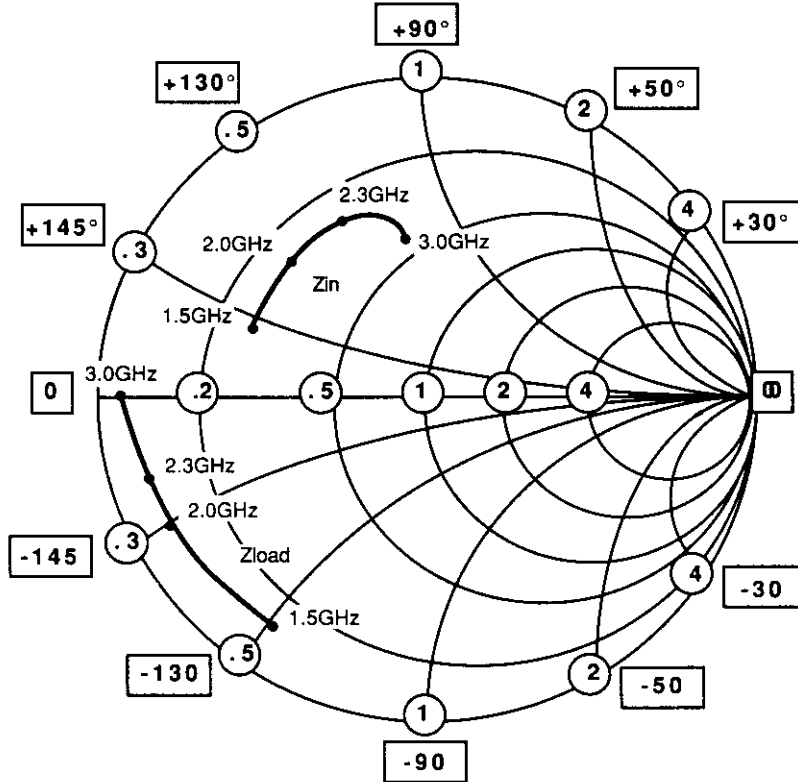
Pout VS Pin VS FREQUENCY

Vcc=28V, Pin=0.2W

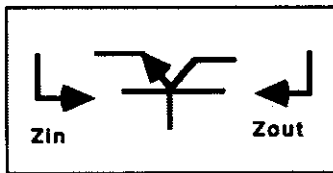


SMITH CHART 3001

NORMALIZED IMPEDANCE AND ADMITTANCE COORDINATES



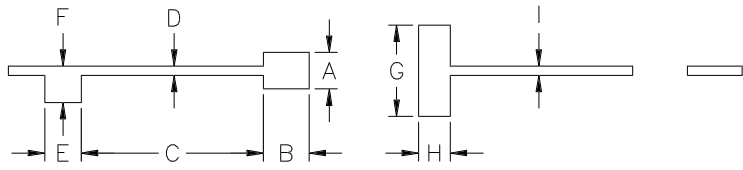
NORMALIZED TO A 50 OHM SYSTEM.



FREQUENCY MHz	R	Zin JX	FREQUENCY MHz	R	Zload JX
1.5	15	14	1.5	6	25
2.0	16	20	2.0	5	15
2.3	17	27	2.3	4.5	10
3.0	19	32	3.0	4	0

REVISIONS

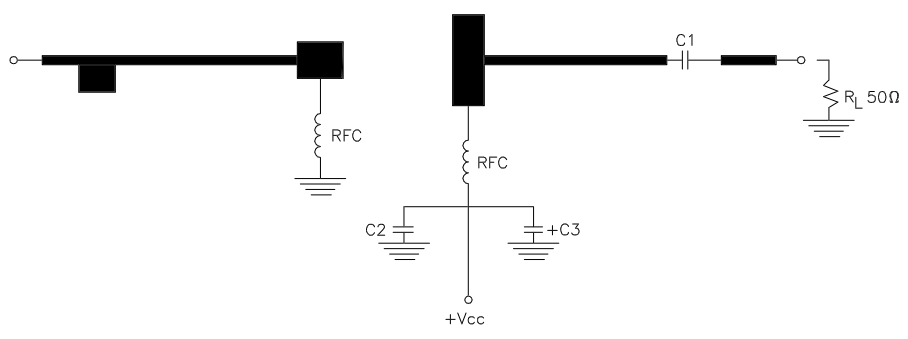
ZONE	REV	DESCRIPTION	DATE	APPROVED
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DIM	INCHES
A	.200
B	.250
C	1.000
D	.500
E	.200
F	.200
G	.500
H	.175
I	.050

3001 TEST AMPLIFIER

f = 3000 MHz



— = Microstrip on 0.020" Teflon Fiberglass, Er=2.55
 C1,C2 = ATC 'A' 47pf
 C3 = 10μfd @ 35 Volts



CAGE	DWG NO.	REV
OPJR2	3001	A
SCALE	1/1	SHEET